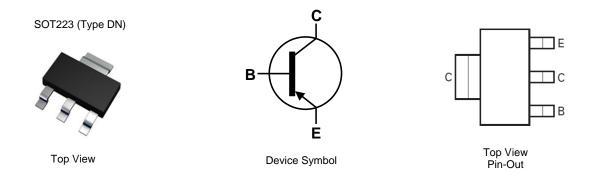


#### Features

- BV<sub>CEO</sub> > -12V
- I<sub>C</sub> = -6A High Continuous Collector Current
- I<sub>CM</sub> = -20A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -170mV @ -2A</li>
- h<sub>FE</sub> Specified up to -10A for a High Gain Hold Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>)

#### **Mechanical Data**

- Package: SOT223 (Type DN)
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>(2)</sup>
- Weight: 0.112 grams (Approximate)



#### Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel size (inches)	Tape width (mm)	Packing	
	Гаскауе	Warking		Tape width (mm)	Quantity	Carrier
FZT968TA	SOT223 (Type DN)	FZT968	7	12	1,000	Reel

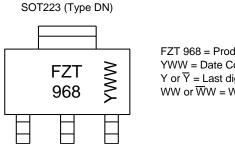
Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### Marking Information



FZT 968 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last digit of year (ex: 3 = 2023) WW or  $\overline{W}W$  = Week code (01~53)



### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-15	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-12	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6	V
Continuous Collector Current	I <sub>C</sub>	-6	А
Peak Pulse Current	I <sub>CM</sub>	-20	А

#### **Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	5	3.0 24	W	
Linear derating factor	(Note 6)	P <sub>D</sub> -	1.6 12.8	mW /°C	
Thermal Desistance, lunction to Archient	(Note 5)	R <sub>0JA</sub>	42		
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>0JA</sub>	78	°C/W	
Thermal Resistance Junction to Lead	(Note 7)	R <sub>θJL</sub>	8.8	-	
Operating and Storage Temperature Range	<u>.</u>	TJ, TSTG	-55 to +150	°C	

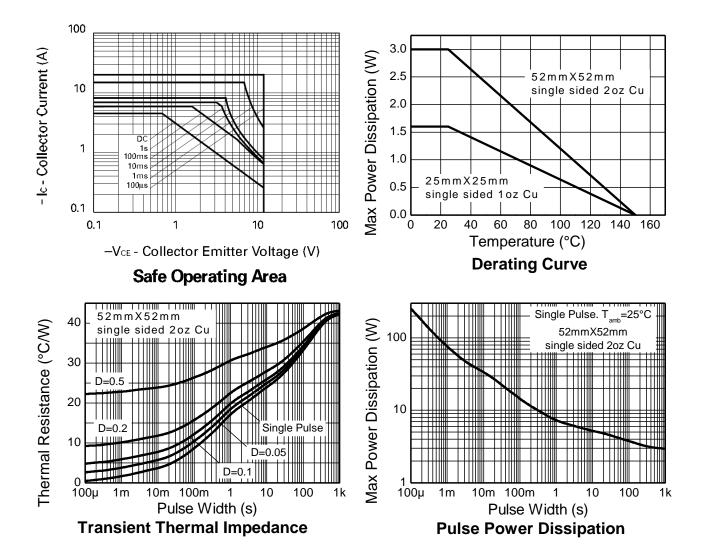
### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air Notes: For a device mounted with the contector lead on S2mm x S2mm 202 copper that is conditions whilst operating in steady-state.
Same as note 5, except the device is mounted on 25mm x 25mm 1oz copper.
Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating Information**





## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-15	-28	—	V	I <sub>C</sub> = -100μA	
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-12	-20	—	V	I <sub>C</sub> = -10mA	
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-6	-8	_	V	I <sub>E</sub> = -100μΑ	
Collector Cutoff Current	I <sub>CBO</sub>		—	-10 -1	nΑ μΑ	V <sub>CB</sub> = -12V V <sub>CB</sub> = -12V, T <sub>A</sub> = +100°C	
Emitter Cutoff Current	I <sub>EBO</sub>	_	—	-10	nA	V <sub>EB</sub> = -6V	
		300	450	—		$I_{C} = -10mA, V_{CE} = -1V$	
	hfe	300	450	1000		$I_{C} = -500 \text{mA}, V_{CE} = -1 \text{V}$	
DC current transfer Static ratio (Note 9)		200	300			$I_{C} = -5A, V_{CE} = -1V$	
		150	240			$I_{C} = -10A, V_{CE} = -1V$	
		_	50			$I_{C} = -20A, V_{CE} = -1V$	
		_	-65	-130	mV	$I_{C} = -500 \text{mA}, I_{B} = -5 \text{mA}$	
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	_	-132	-170		$I_{C} = -2A, I_{B} = -50mA$	
		_	-360	-450		$I_{C} = -6A, I_{B} = -250mA$	
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	—	-1.05	-1.2	V	$I_{C} = -6A, I_{B} = -250mA$	
Base-Emitter Turn-on Voltage (Note 9)	V <sub>BE(on)</sub>	—	-0.87	-1.05	V	$I_{C} = -6A, V_{CE} = -1V$	
Transitional Frequency (Note 9)	f <sub>T</sub>		80	_	MHz	$I_{C} = -100 \text{mA}, V_{CE} = -10 \text{V},$ f = 50MHz	
Output capacitance	Cobo	_	161		pF	V <sub>CB</sub> = -20V, f = 1MHz	
Switching Time	t <sub>on</sub>	—	120	—	20	$V_{CC} = -10V, I_C = -4A,$	
	t <sub>off</sub>	—	116	—	ns	$I_{B1} = -I_{B2} = -400 \text{mA}$	

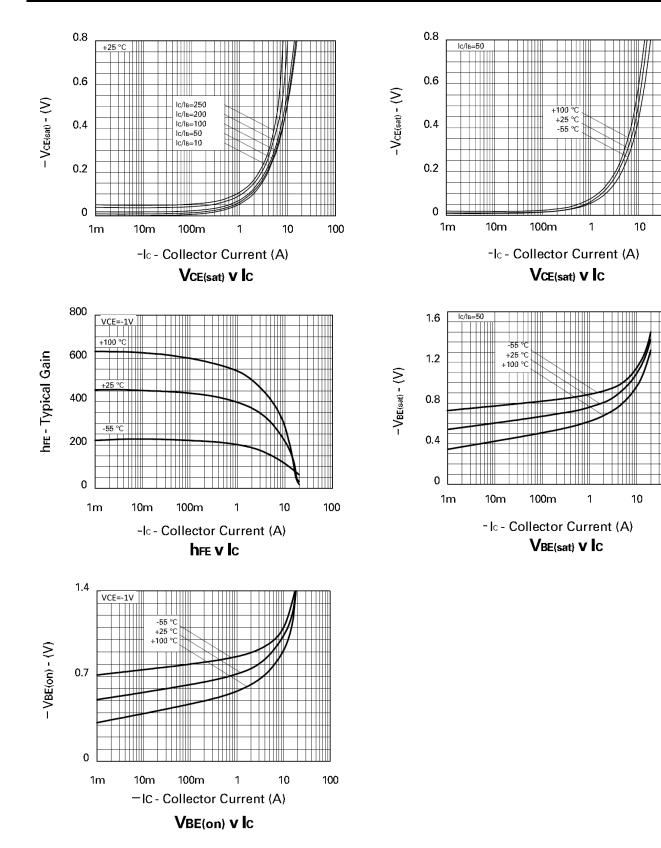
Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



100

100

## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

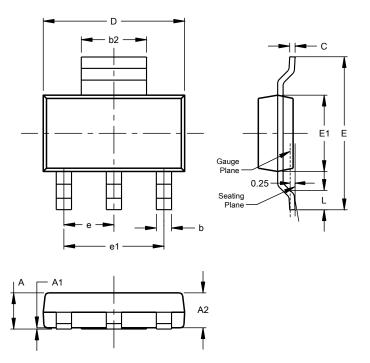




## **Package Outline Dimensions**

Please see https://www.diodes.com/design/support/packaging/diodes-packaging/ for the latest version.

#### SOT223 (Type DN)



SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
c	0.20	0.32			
D	6.30	6.70			
ш	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All [	All Dimensions in mm				

## **Suggested Pad Layout**

Please see https://www.diodes.com/design/support/packaging/diodes-packaging/ for the latest version.

# 

Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

SOT223 (Type DN)



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